

Description

The HXY3401AI uses advanced trench technology

to provide excellent $R_{DS(ON)}$, This device is suitable

for use as a load switch or in PWM applications.

General Features

 V_{DS} = -30V, I_{D} = -4.2A

 $R_{DS(ON)} < 55m\Omega @ V_{GS}$ =-10V

 $R_{DS(ON)} < 75m\Omega @ V_{GS}=-4.5V$

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HXY3401AI	SOT-23	A19T	3000

Absolute Maximum Ratings (TA=25[°]C unless otherwise noted)

Symbol	Parameter	Limit	Unit	
VDS	Drain-Source Voltage	-30	V	
Vgs	Gate-Source Voltage	±12	V	
ID	Drain Current-Continuous	-4.2	A	
DM	Drain Current-Pulsed (Note 1)	-30	A	
PD	Maximum Power Dissipation	1.2	W	
TJ,Tstg	Operating Junction and Storage Temperature Range	-55 To 150	°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	104	°C/W	





D C C S

P-Channel MOSFET



Electrical Characteristics (TA=25°C unless otherwise noted)

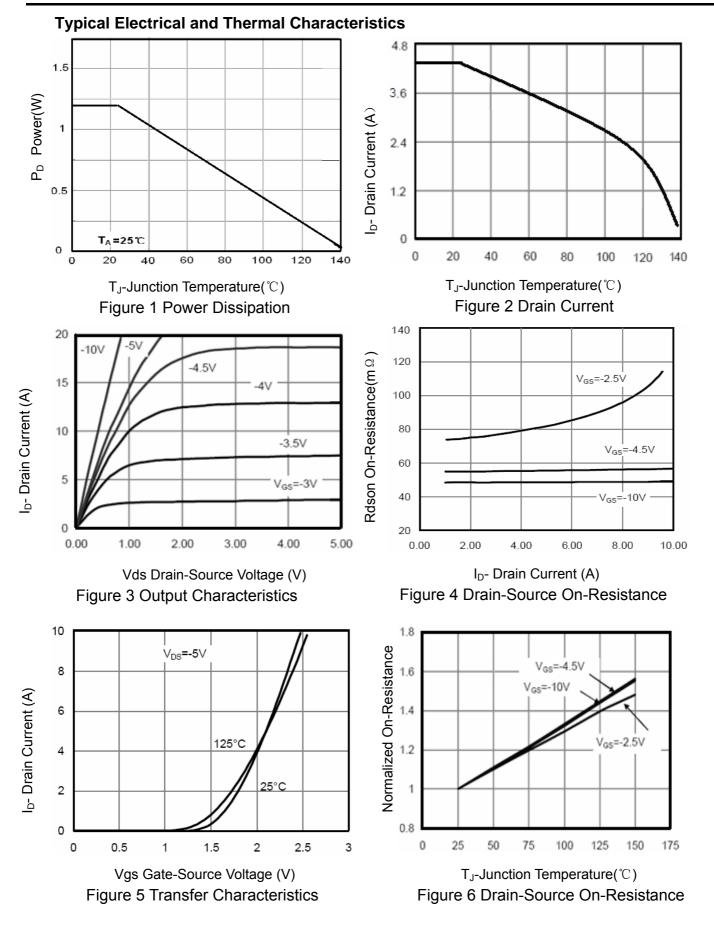
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30		-	V
Zero Gate Voltage Drain Current	ldss	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	lgss	V _{GS} =±10V,V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	V _{DS} =V _{GS} ,I _D =-250µA	-0.7	-1	-1.3	V
	Rds(on)	V _{GS} =-10V, I _D =-4.2A	-	45	55	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4A	-	56	75	mΩ
		V _{GS} =-2.5V, I _D =-1A		72	90	mΩ
Forward Transconductance	gfs	V _{DS} =-5V,I _D =-4.2A	-	10	-	S
Input Capacitance	Clss		-	880	-	PF
Output Capacitance	Coss	V _{DS} =-15V,V _{GS} =0V,	-	105	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	65	-	PF
Turn-on Delay Time	td(on)		-	7	-	nS
Turn-on Rise Time	tr	VDD=-15V.ID=-4.2A VGS=-	-	3	-	nS
Turn-Off Delay Time	td(off)	10V,R _{GEN} =6Ω	-	30	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg		-	8.5	-	nC
Gate-Source Charge	Qgs	V _{DS} =-15V,I _D =-4.2A,V _{GS} =- 4.5V	-	1.8	-	nC
Gate-Drain Charge	Q _{gd}		-	2.7	-	nC
Drain-Source Diode Characteristics	I	1	1	I		
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =-4.2A	_	-	-1.2	V

1、Repetitive Rating: Pulse width limited by maximum junction temperature. 2、Surface Mounted on FR4 Board, t \leq 10 sec.

3 v Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production

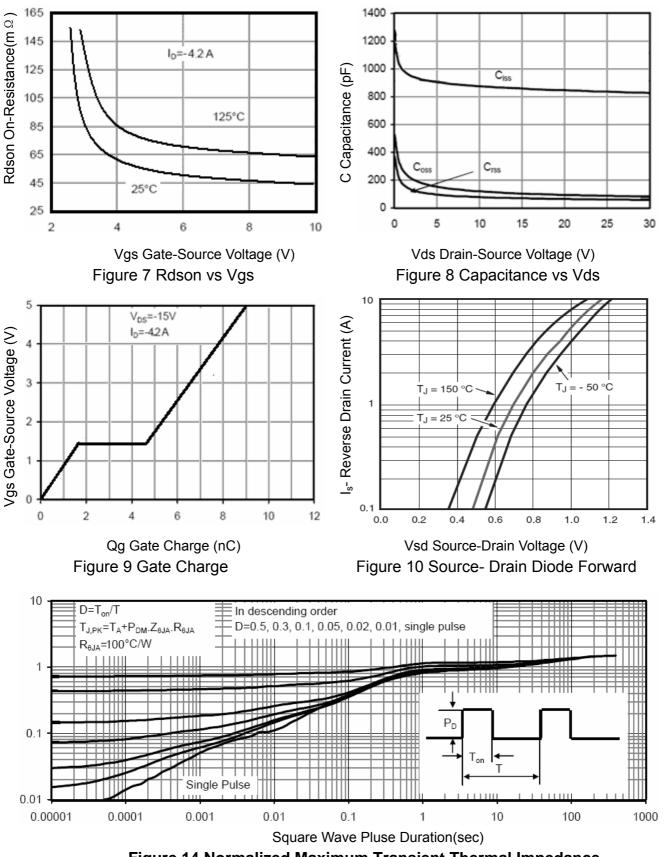


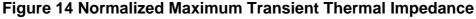




HXY3401AI

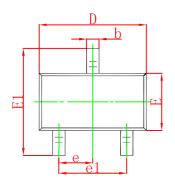
P-Channel Enhancement Mode MOSFET

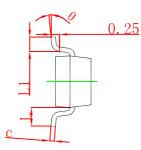


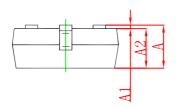




SOT-23 Package Outline Dimensions

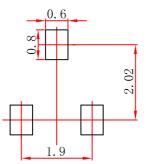






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
e	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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